

Noninverting Buffer with Open Drain Output

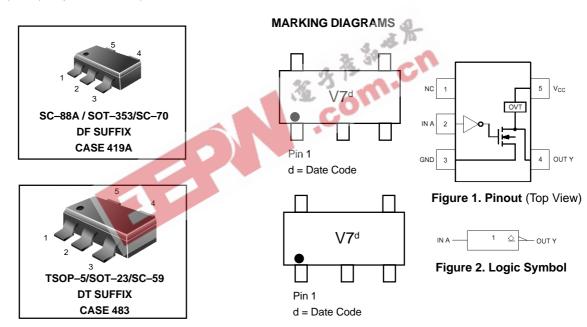
MC74VHC1G07

The MC74VHC1G07 is an advanced high speed CMOS buffer with open drain output fabricated with silicon gate CMOS technology. It achieves high speed operation similar to equivalent Bipolar Schottky TTL while maintaining CMOS low power dissipation.

The internal circuit is composed of three stages, including a buffer and an open drain output which provides the capability to set the output switching level. This allows the MC74VHC1G07 to be used to interface 5 V circuits to circuits of any voltage between V cc and 7 V using an external resistor and power supply.

The MC74VHC1G07 input structure provides protection when voltages up to 7 V are applied, regardless of the supply voltage.

- High Speed: $t_{PD} = 3.8 \text{ ns}$ (Typ) at $V_{CC} = 5 \text{ V}$
- Low Internal Power Dissipation: I cc = 2 mA (Max) at T A = 25°C
- Power Down Protection Provided on Inputs
- Pin and Function Compatible with Other Standard Logic Families
- Chip Complexity: FET = 105; Equivalent Gate = 26



| PIN ASSIGNMENT | | | | | | | |
|----------------|--------------------|--|--|--|--|--|--|
| 1 | NC | | | | | | |
| 2 | IN A | | | | | | |
| 3 | GND | | | | | | |
| 4 | OUT \overline{Y} | | | | | | |
| 5 | V cc | | | | | | |

FUNCTION TABLE

| Inputs | Output |
|--------|--------|
| Α | Y |
| L | L |
| Н | Z |

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.



MC74VHC1G07

MAXIMUM RATINGS

| Symbol | Para | ameter | Value | Unit |
|------------------|--------------------------------|---|----------------|------|
| V cc | DC Supply Voltage | | - 0.5 to + 7.0 | V |
| V IN | DC Input Voltage | | - 0.5 to +7.0 | V |
| V _{OUT} | DC Output Voltage | | - 0.5 to +7.0 | V |
| Lik | Input Diode Current | | -20 | mA |
| I ok | Output Diode Current | V_{out} < GND; V_{out} > V_{cc} | +20 | mA |
| I _{OUT} | DC Output Current, per Pin | | + 25 | mA |
| I _{cc} | DC Supply Current, V cc and | d GND | +50 | mA |
| P _D | Power dissipation in still air | SC-88A, TSOP-5 | 200 | mW |
| θ _{JA} | Thermal resistance | SC-88A, TSOP-5 | 333 | °C/W |
| ΤL | Lead Temperature, 1 mm fr | om Case for 10 s | 260 | °C |
| Τ _J | Junction Temperature Unde | er Bias | + 150 | °C |
| T stg | Storage temperature | | -65 to +150 | °C |
| V _{ESD} | ESD Withstand Voltage | Human Body Model (Note 2) | >2000 | V |
| | | Machine Model (Note 3) | > 200 | |
| | | Charged Device Model (Note 4) | N/A | |
| I LATCH-UP | Latch–Up Performance A | bove V cc and Below GND at 125°C (Note 5) | ± 500 | mA |

^{1.} Maximum Ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute-maximum-rated conditions is not implied. Functional operation should be restricted to the Recommended Operating Conditions.

Tested to EIA/JESD22–A114–A

Tested to JESD22–C101–A

Tested to EIA/JESD78

- 2. Tested to EIA/JESD22-A114-A
- 3. Tested to EIA/JESD22-A115-A
- 4. Tested to JESD22-C101-A
- 5. Tested to EIA/JESD78

RECOMMENDED OPERATING CONDITIONS

| Symbol | Parameter | | Min | Max | Unit | |
|--------------------------------|-----------------------------|----------------------------------|-------------|-------|------|--|
| V _{cc} | DC Supply Voltage | | 2.0 | 5.5 | V | |
| V IN | DC Input Voltage | | 0.0 | 5.5 | V | |
| V _{OUT} | DC Output Voltage | | 0.0 | 7.0 | V | |
| T _A | Operating Temperature Range | | – 55 | + 125 | °C | |
| t _r ,t _f | Input Rise and Fall Time | $V_{CC} = 3.3 \pm 0.3 \text{ V}$ | 0 | 100 | ns/V | |
| | | $V_{CC} = 5.0 \pm 0.5 V$ | 0 | 20 | | |

DEVICE JUNCTION TEMPERATURE VERSUS TIME TO 0.1% BOND FAILURES

| Junction | Time, | Time, |
|----------------|-----------|-------|
| Temperature °C | Hours | Years |
| 80 | 1,032,200 | 117.8 |
| 90 | 419,300 | 47.9 |
| 100 | 178,700 | 20.4 |
| 110 | 79,600 | 9.4 |
| 120 | 37,000 | 4.2 |
| 130 | 17,800 | 2.0 |
| 140 | 8,900 | 1.0 |

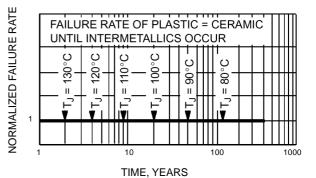


Figure 3. Failure Rate vs. Time **Junction Temperature**



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DC ELECTRICAL CHARACTERISTICS

| | | | V cc | Т | _A = 25 | °C | T _A ≤ | 85 °C | -55°C≤ | 55°C≤T _A ≤125°C | |
|-----------------|--------------------------------------|--------------------------------------|---------|------|-------------------|------|------------------|--------------|--------|----------------------------|------|
| Symbol | Parameter | Test Conditions | (V) | Min | Тур | Max | Min | Max | Min | Max | Unit |
| V _{IH} | Minimum High-Level | | 2.0 | 1.5 | | | 1.5 | | 1.5 | | V |
| | Input Voltage | | 3.0 | 2.1 | | | 2.1 | | 2.1 | | |
| | | | 4.5 | 3.15 | | | 3.15 | | 3.15 | | |
| | | | 5.5 | 3.85 | | | 3.85 | | 3.85 | | |
| V _{IL} | Maximum Low-Level | | 2.0 | | | 0.5 | | 0.5 | | 0.5 | V |
| | Input Voltage | | 3.0 | | | 0.9 | | 0.9 | | 0.9 | |
| | | | 4.5 | | | 1.35 | | 1.35 | | 1.35 | |
| | | | 5.5 | | | 1.65 | | 1.65 | | 1.65 | |
| V _{OH} | Minimum High-Level | $V_{IN} = V_{IH} \text{ or } V_{IL}$ | 2.0 | 1.9 | 2.0 | | 1.9 | | 1.9 | | V |
| | Output Voltage | $I_{OH} = -50 \mu A$ | 3.0 | 2.9 | 3.0 | | 2.9 | | 2.9 | | |
| | $V_{IN} = V_{IH} \text{ or } V_{IL}$ | | 4.5 | 4.4 | 4.0 | | 4.4 | | 4.4 | | |
| | | $V_{IN} = V_{IH} \text{ or } V_{IL}$ | | | | | | | | | |
| | | $I_{OH} = -4 \text{ mA}$ | 3.0 | 2.58 | | | 2.48 | | 2.34 | | |
| | | $I_{OH} = -8 \text{ mA}$ | 4.5 | 3.94 | | 4 | 3.80 | | 3.66 | | |
| V _{OL} | Maximum Low-Level | $V_{IN} = V_{IH} \text{ or } V_{IL}$ | 2.0 | | 0.0 | 0.1 | 110 | 0.1 | | 0.1 | V |
| | Output Voltage | $I_{OL} = 50 \mu A$ | 3.0 | | 0.0 | 0.1 | -10 | 0.1 | | 0.1 | |
| | $V_{IN} = V_{IH} \text{ or } V_{IL}$ | | 4.5 | 2 | 0.0 | 0.1 | | 0.1 | | 0.1 | |
| | | $V_{IN} = V_{IH} \text{ or } V_{IL}$ | | | | 100 | | | | | |
| | | $I_{OL} = 4 \text{ mA}$ | 3.0 | | | 0.36 | | 0.44 | | 0.52 | |
| | | $I_{OL} = 8 \text{ mA}$ | 4.5 | | | 0.36 | | 0.44 | | 0.52 | |
| I _{IN} | Maximum Input | $V_{IN} = 5.5 \text{ V or GND}$ | 0 to5.5 | | | ±0.1 | | ±1.0 | | ±1.0 | μΑ |
| | Leakage Current | | | | | | | | | | |
| I _{cc} | Maximum Quiescent | $V_{IN} = V_{CC}$ or GND | 5.5 | | | 2.0 | | 20 | | 40 | μΑ |
| | Supply Current | | | | | | | | | | |
| I OPD | Maximum Off-state | V _{OUT} = 5.5 V | 0 | | | 0.25 | | 2.5 | | 5.0 | μΑ |
| | Leakage Current | | | | | | | | | | |

AC ELECTRICAL CHARACTERISTICS C $_{load}$ = 50 pF, Input t $_{r}$ = t $_{f}$ = 3.0 ns

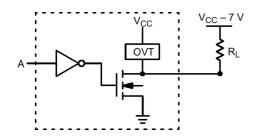
| | | | Т | T _A = 25 °C | | T _A ≤ | 85 °C | –55 °C to 125 °C | | |
|--------|--|--|-----|-------------------------------|------|------------------|--------------|--------------------------------|------|------|
| Symbol | Parameter | Test Conditions | Min | Тур | Max | Min | Max | Min | Max | Unit |
| t PZL | Maximum Output | V CC = 3.3 ± 0.3 V C L = 15 pF | | 5.0 | 7.1 | | 8.5 | | 10.0 | ns |
| | Enable Time, Input A to \overline{Y} | R L = R I = 500 Ω C L = 50 pF | | 7.5 | 10.6 | | 12.0 | | 14.5 | |
| | | $V CC = 5.0 \pm 0.5 V C L = 15 pF$ | | 3.8 | 5.5 | | 6.5 | | 8.0 | |
| | | R L = R I = 500 Ω $C L = 50 pF$ | | 5.3 | 7.5 | | 8.5 | | 10.0 | |
| t PLZ | Maximum Output Disable Time | $V CC = 3.3 \pm 0.3 V C L = 50 pF$ $R L = R I = 500 \Omega$ | | 7.5 | 10.6 | | 12.0 | | 14.5 | ns |
| | | $V CC = 5.0 \pm 0.5 V C L = 50 pF$ R L = R I = 500 Ω | | 5.3 | 7.5 | | 8.5 | | 10.0 | |
| C IN | Maximum Input | | | 4 | 10 | | 10 | | 10 | pF |
| | Capacitance | | | | | | | | | |

| | | Typical @ 25°C, V _{cc} = 5.0 V | |
|------|--|---|----|
| C PD | Power Dissipation Capacitance (Note 6) | 18 | pF |

^{6.} C $_{PD}$ is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: $I_{CC(OPR)} = C_{PD}XV_{CC}Xf_{in} + I_{CC}.C_{PD}$ is used to determine the noload dynamic power consumption; $P_D = C_{PD}XV_{CC}^2Xf_{in} + I_{CC}XV_{CC}$.



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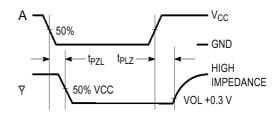
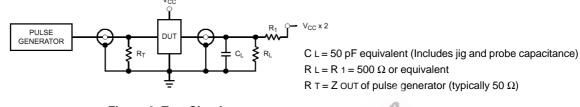
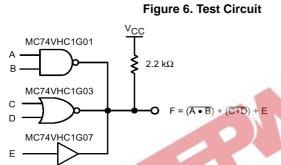


Figure 4. Output Voltage Mismatch Application

Figure 5. Switching Waveforms





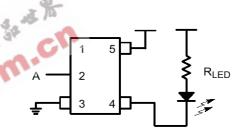


Figure 8. LED Driver

Figure 7. Complex Boolean Functions

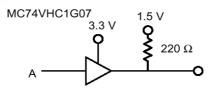


Figure 9. GTL Driver

DEVICE ORDERING INFORMATION

| | | | Device I | Nomenclatu | re | | | |
|------------------------|-------------------------------|----------------------------------|----------|--------------------|-------------------|-------------------------|---|-------------------------------|
| Device Order Number | Logic Circuit Indicator | rcuit Range Technology Functi | | Device Function | Package Suffix | Tape and Reel Suffix | Package Type (Name/SOT#/ Common Name) | Tape and Reel Size |
| MC74VHC1G07DFT1 | MC | 74 | VHC1G | 07 | DF | T1 | SC-70/SC-88A/ SOT-353 | 178 mm (7 in) 3000 Unit |
| MC74VHC1G07DFT2 | MC | 74 | VHC1G | 07 | DF | T2 | SC-70/SC-88A/ SOT-353 | 178 mm (7 in) 3000 Unit |
| MC74VHC1G07DFT4 | MC | 74 | VHC1G | 07 | DF | T4 | SC-70/SC-88A/ SOT-353 | 330 mm (13 in) 10,000 Unit |
| MC74VHC1G07DTT1 | МС | 74 | VHC1G | 07 | DT | T1 | SOT-23/TSOPS/ SC-59 | 178 mm (7 in) 3000 Unit |
| MC74VHC1G07DTT3 | MC | 74 | VHC1G | 07 | DT | Т3 | SOT-23/TSOPS/ SC-59 | 330 mm (13 in) 10,000 Unit |